

isc P-Channel MOSFET Transistor

IRF9Z34NL

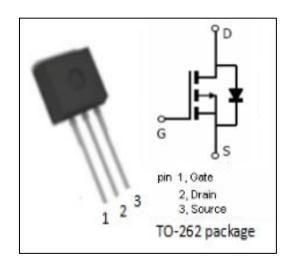
·FEATURES

- Static drain-source on-resistance: R_{DS}(on)≤100mΩ(@V_{GS}= -10V; I_D= -10A)
- Advanced trench process technology
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

• Fast switching application.





• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	-55	V
V _{GS}	Gate-Source Voltage	±20	V
I _D	Drain Current-Continuous	-19	А
P _D	Total Dissipation @T _C =25°C	68	W
Tj	Max. Operating Junction Temperature	-55~175	°C
T _{stg}	Storage Temperature	-55~175	°C

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(j-c)	Channel-to-case thermal resistance	2.2	°C/W

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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = -250 μ A	-55		V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D = -250 μ A	-2	-4	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = -10V; I _D = -10A		100	$m\Omega$
Igss	Gate-Source Leakage Current	V _{GS} = ±20V; V _{DS} = 0V		±100	nA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = -55V; V _{GS} = 0V		-25	μА
V_{SD}	Diode forward voltage	I _S = -10A, V _{GS} = 0V		-1.6	V



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